

HEX BUFFERS WITH OPEN DRAIN OUTPUTS

Description

The 74LVC07A provides six independent open-drain buffers. The device is designed for operation with a power supply range of 1.65V to 5.5V. The inputs are tolerant to 5.5V allowing this device to be used in a mixed voltage environment. The device is fully specified for partial power down applications using IOFF. The IOFF circuitry disables the output preventing damaging current backflow when the device is powered down. The outputs can be connected to implement active-low wired-OR or active-high wired-AND functions.

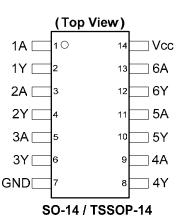
The gates perform the positive Boolean function:



Features

- Wide Supply Voltage Range from 1.65V to 5.5V
- Sinks 24mA at V_{CC} = 3.3V
- CMOS low power consumption
- IOFF Supports Partial-Power-Down Mode Operation
- Inputs or outputs accept up to 5.5V
- Inputs can be driven by 3.3V or 5.5V allowing for voltage translation applications.
- ESD Protection Exceeds JESD 22
 - 200-V Machine Model (A115-A)
 - 2000-V Human Body Model (A114-A)
 - Exceeds 1000-V Charged Device Model (C101C)
- Latch-Up Exceeds 250 mA per JESD 78, Class II
- Range of Package Options SO-14 and TSSOP-14
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)

Pin Assignments



Applications

- Voltage Level Shifting
- General Purpose Logic
- Power Down Signal Isolation
- Wide array of products such as:
 - PCs, networking, notebooks, ultrabooks, netbooks
 - Computer peripherals, hard drives, CD/DVD ROM
 - TV, DVD, DVR, set top box

Notes:

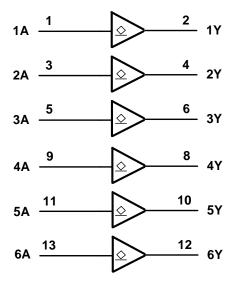
- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.
- 2. See http://www.diodes.com for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.



Pin Descriptions

Pin Number	Pin Name	Description
1	1A	Data Input
2	1Y	Data Output
3	2A	Data Input
4	2Y	Data Output
5	3A	Data Input
6	3Y	Data Output
7	GND	Ground
8	4Y	Data Output
9	4A	Data Input
10	5Y	Data Output
11	5A	Data Input
12	6Y	Data Output
13	6A	Data Input
14	V _{CC}	Supply Voltage

Logic Diagram



Function Table

Inputs	Outputs
Α	Υ
L	L
Н	Z



$\textbf{Absolute Maximum Ratings} \text{ (Note 4) } (@T_A = +25^{\circ}\text{C}, \text{ unless otherwise specified.)}$

Symbol	Description	Rating	Unit
ESD HBM	Human Body Model ESD Protection	2	KV
ESD CDM	Charged Device Model ESD Protection	1	KV
ESD MM	Machine Model ESD Protection	200	V
Vcc	Supply Voltage Range	-0.5 to +6.5	V
VI	Input Voltage Range	-0.5 to +6.5	V
Vo	Voltage applied to output in high impedance or I _{OFF} state	-0.5 to +6.5	V
Vo	Voltage applied to output in high or low state	-0.3 to V _{CC} +0.5	V
I_{IK}	Input Clamp Current V _I < 0	-50	mA
I _{OK}	Output Clamp Current V _O < 0	-50	mA
lo	Continuous output current	50	mA
	Continuous current through Vdd or GND	±100	mA
TJ	Operating Junction Temperature	-40 to +150	°C
T _{STG}	Storage Temperature	-65 to +150	°C
P _{TOT}	Total Power Dissipation	500	mW

Note: 4. Stresses beyond the absolute maximum may result in immediate failure or reduced reliability. These are stress values and device operation should be within recommend values.

Recommended Operating Conditions (Note 5) (@TA = +25°C, unless otherwise specified.)

Symbol	Parameter	Conditions	Min	Max	Unit	
V _{CC}	Supply Voltage		1.65	5.5	V	
VI	Input Voltage		0	5.5	V	
.,		Active Mode	0	Vcc	V	
Vo	Output Voltage	V _{CC} = 0V; Power Down Mode	0	5.5	V	
A./A./		V _{CC} = 1.65V to 2.7V		20	0.4	
Δt/ΔV	Input transition rise or fall rate	V _{CC} = 2.7V to 5.5V		10	ns/V	
T _A	Operating free-air temperature		-40	+125	°C	

Notes: 5. Unused inputs should be held at V_{CC} or Ground.



Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

			.,	T _A = -40°C	C to +85°C	T _A = -40°C	to +125°C	
Symbol	Parameter	Test Conditions	V _{CC}	Min	Max	Min	Max	Unit
			1.65V to 1.95V	0.65 X V _{CC}		0.65 X V _{CC}		
\	High-level Input		2.3V to 2.7V	1.7		1.6		
V_{IH}	Voltage		2.7V to 3.6V	2.0		2.0		V
			4.5V to 5.5V	0.7 X V _{CC}		2.0		
			1.65V to 1.95V		0.35 X V _{CC}		0.35 X V _{CC}	
VIL	Low-level input		2.3V to 2.7V		0.7		0.7	\ /
VIL	voltage		2.7V to 3.6V		0.8		0.8	V
			4.5V to 5.5V		0.3 X V _{CC}		0.3 X V _{CC}	
		$I_{OL} = 100 \mu A$	1.65V to 5.5V		0.2		0.3	
		I _{OL} = 4mA	1.65V		0.45		0.6	
		I _{OL} = 8mA	2.3V		0.70		0.85	
V_{OL}	Low-level Output Voltage	40 4	2.7V		0.40		0.6	V
	Voltage	I _{OL} = 12mA	3.0V		0.55		0.6	
		I _{OL} = 24mA	3.0V		0.55		0.6	
		I _{OL} = 32mA	4.5V		0.55		0.6	
lı	Input Current	$V_I = GND \text{ to } 5.5V$	3.6V		± 5		± 20	μΑ
l _{OZ}	Z State Leakage Current	$V_O = GND \text{ or}$ 5.5V	3.6V		±10		±20	μΑ
l _{OFF}	Power Down Leakage Current	V_I or $V_O = 0V$ to 3.6V	0		10		20	μΑ
Icc	Supply Current	$V_I = GND \text{ or } V_{CC}$ $I_O = 0$	3.6V		10		40	μΑ



Switching Characteristics

Corrects at	Danamatan	Test	Test		Γ _A = +25°C	;	-40°C to	+85°C	-40°C to	+125°C	11:4	
Symbol	Parameter	Conditions	V _{cc}	Min	Тур	Max	Min	Max	Min	Max	Unit	
				1.65V to1.95V	0.3	2.9	5.7	0.3	5.8	0.3	7.6	
	Propagation	Figure 1	2.3V to 2.7V	0.3	2.6	4.1	0.3	4.7	0.3	5.5		
t _{PLZ} /t _{PZL}	Delay A _N to Y _N		2.7V	0.3	2.5	4.0	0.3	4.5	0.3	5.0	ns	
			3V to 3.6V	0.3	2.3	3.5	0.3	3.7	0.3	5.0		
			4.5V to 5.5V	0.3	1.7	3.2	0.3	3.4	0.3	4.5		

Operating Characteristics (@T_A = +25°C, unless otherwise specified.)

	Parameter	Test Conditions	V _{CC} = 1.8V Typ	V _{CC} = 2.5V Typ	V _{CC} = 3.3V Typ	V _{CC} = 5V Typ	Unit
$C_{\sf pd}$	Power dissipation capacitance per gate	f = 10 MHz	7.0	7.5	8.0	8.6	pF
Cı	Input Capacitance	$V_I = V_{CC} - or$ GND	4	4	4	4	pF

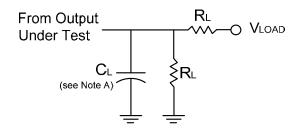
Package Characteristics

Symbol	Parameter	Test Conditions	V _{cc}	Min	Тур	Max	Unit
	Thermal Resistance	SO-14	(1)		TBD		°C/W
θЈΑ	Junction-to-Ambient	TSSOP-14	(Note 6)		159		
	Thermal Resistance	SO-14	(1) (0)		TBD		00.004
θ _{JC}	Junction-to-Case	TSSOP-14	(Note 6)		25		°C/W

Note: 6. Test condition for SO-14 and TSSOP-14: Device mounted on FR-4 substrate PC board, 2oz copper, with minimum recommended pad layout.

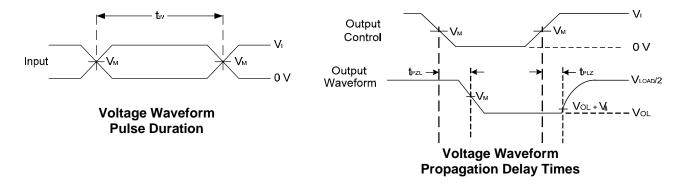


Parameter Measuement Information



TEST	Condition
t _{PLZ} (see Note E)	V_{LOAD}
t _{PZL} (see Note D)	V_{LOAD}

V	Inputs		, , , , , , , , , , , , , , , , , , ,		CL	ь	V.	
V _{CC}	VI	t _r /t _f	٧M	V _M V _{LOAD}		R_{L}	V Δ	
1.8V±0.15V	V _{CC}	≤2ns	V _{CC} /2	2 X V _{CC}	30pF	1ΚΩ	0.15V	
2.5V±0.2V	V _{CC}	≤2ns	V _{CC} /2	2 X V _{CC}	30pF	500Ω	0.15V	
2.7V	2.7V	≤2ns	1.5V	6V	50pF	500Ω	0.3V	
3.3V±0.3V	3V	≤2.5ns	1.5V	6V	50pF	500Ω	0.3V	
5V±0.5V	V _{CC}	≤2.5ns	V _{CC} /2	2 X V _{CC}	50pF	500Ω	0.3V	



Notes: A. Includes test lead and test apparatus capacitance.

B. All pulses are supplied at pulse repetition rate ≤ 10 MHz

C. The inputs are measured one at a time with one transition per measurement.

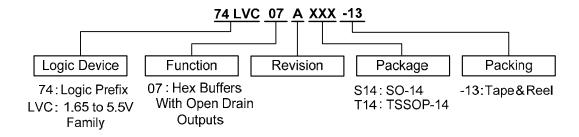
D. t_{PZL} is measured at V_{M} .

E. $t_{PLZ}\,$ is measured at V_{OL} + V_{Δ}

Figure 1. Load Circuit and Voltage Waveforms



Ordering Information

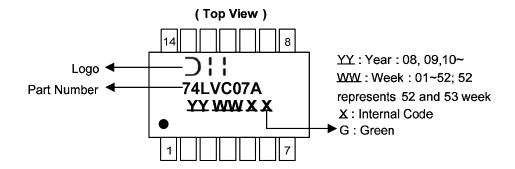


	Dart Number	Package	Packaging	13" Tape and Reel		
	Part Number	Code	(Note 7)	Quantity	Part Number Suffix	
,	74LVC07AS14-13	S14	SO-14	2500/Tape & Reel	-13	
-	74LVC07AT14-13	T14	TSSOP-14	2500/Tape & Reel	-13	

Notes: 7. The taping orientation and tape details can be found at http://www.diodes.com/datasheets/ap02007.pdf

Marking Information

(1) SO-14, TSSOP-14

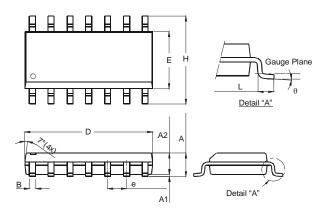


Part Number	Package
74LVC07AS14	SO-14
74LVC07AT14	TSSOP-14



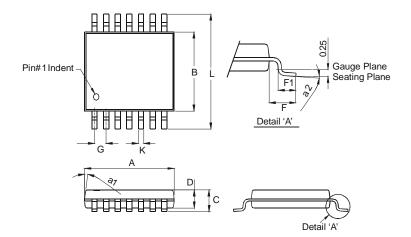
Package Outline Dimensions (All dimensions in mm.)

Package Type: SO-14



SO-14			
Dim	Min	Max	
Α	1.47	1.73	
A1	0.10	0.25	
A2	1.45 Typ		
В	0.33	0.51	
D	8.53	8.74	
Е	3.80	3.99	
е	1.27 Typ		
Н	5.80	6.20	
L	0.38	1.27	
θ	0°	8°	
All Dimensions in mm			

Package Type: TSSOP-14

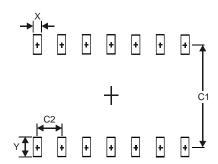


TSSOP-14			
Dim	Min	Max	
a1	7° (4X)		
a2	0°	8°	
Α	4.9	5.10	
В	4.30	4.50	
С	_	1.2	
D	0.8	1.05	
F	1.00 Typ		
F1	0.45	0.75	
G	0.65 Typ		
K	0.19	0.30	
L	6.40 Typ		
All Dimensions in mm			



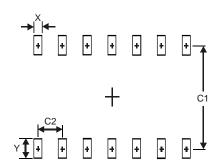
Suggested Pad Layout

Package Type: SO-14



Dimensions	Value (in mm)	
Х	0.60	
Y	1.50	
C1	5.4	
C2	1.27	

Package Type: TSSOP-14



Dimensions	Value (in mm)
Х	0.45
Y	1.45
C1	5.9
C2	0.65



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Contact Us:

> Address:

401 Building No.5, JiuGe Business Center, Lane 2301, Yishan Rd Minhang District, Shanghai , China

> Sales:

Direct +86 (21) 6401-6692

Email amall@ameya360.com

QQ 800077892

Skype ameyasales1 ameyasales2

Customer Service :

Email service@ameya360.com

Partnership :

Tel +86 (21) 64016692-8333

Email mkt@ameya360.com